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Analog High Speed Coupler, High Noise Immunity, 1 MBd, SOP-5 Package



DESCRIPTION

The VOM452T and VOM453T, high speed optocouplers, each consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector and a high speed transistor. The photo detector is junction isolated from the transistor to reduce miller capacitance effects. The open collector output function allows circuit designers to adjust the load conditions when interfacing with different logic systems such as TTL, CMOS, etc.

Because the VOM452T and VOM453T have a Faraday shield on the detector chip, it can also reject and minimize high input to output common mode transient voltages. There is no base connection, further reducing the potential electrical noise entering the package.

The VOM452T and VOM453T are packaged in industry standard SOP-5 packages and are suitable for surface mounting.

This an ideal solution for Industrial communication bus isolation, as well as isolated drive circuit applications such as IPM (intelligent power module) drivers.

FEATURES

Surface mountable

- Industry standard SOP-5 footprint
- Compatible with infrared vapor phase reflow and wave soldering processes
- Isolation test voltage, 3750 V_{RMS}
- Very high common mode transient immunity: 15 000 V/ μ s at V_{CM} = 1500 V guaranteed (VOM453T)
- High speed: 1 MBd
- TTL compatible
- Open collector output
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Fieldbus communication and control
- Logic ground isolation
- Analog signal ground isolation
- Replace pulse transformers
- IPM (intelligent power module) drivers

AGENCY APPROVALS

- UL1577, file no. E52744
- cUL file no. E52744, equivalent to CSA bulletin 5A

ORDERING INFORMATION									
v	ο	М	4	5	#	Т	SOP-5		
			PART NUMBE	R			7.21 mm		
AGENCY CER	TIFIED/PACKA	GE			CI	MTI (kV/µs)			
UL, cUL		≥1				≥ 15			
SOP-5		VOM452T VOM453T			VOM453T				

Notes

• For additional information on the available options refer to option information.

• The product is available only on tape and reel.



RoHS



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
INPUT	•							
Reverse voltage		V _R	3	V				
DC forward current		١ _F	25	mA				
Surge forward current	$t_p \le 1 \ \mu s$, 300 pulses/s	I _{FSM}	1	А				
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	45	mW				
OUTPUT								
Supply voltage		Vs	- 0.5 to 30	V				
Output voltage		Vo	- 0.5 to 25	V				
Output current		Ι _Ο	8	mA				
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	100	mW				
COUPLER								
Isolation test voltage between emitter and detector (refer to climate DIN 40046, part 2, Nov. 74)	t = 1 s	V _{ISO}	3750	V _{RMS}				
Pollution degree (DIN VDE 0110)			2					
Creepage distance			≥ 5	mm				
Clearance distance			≥ 5	mm				
Comparative tracking index per DIN IEC 112/VDE 0303, part 1			175					
	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 ^{\circ}\text{C}, \text{ R}_{ISOL} ^{(1)}$	R _{IO}	≥ 10 ¹²	Ω				
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}, \text{ R}_{ISOL} ^{(1)}$	R _{IO}	≥ 10 ¹¹	Ω				
Storage temperature range		T _{stg}	- 55 to + 125	°C				
Ambient temperature range		T _{amb}	- 55 to + 100	°C				
Junction temperature		Tj	100	°C				
Soldering temperature ⁽²⁾	t < 10 s max.		260	°C				

Notes

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

(1) Device considered a two-terminal device: pins 1, and 3 shorted together and pins 4, 5, and 6 shorted together.

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices.



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ELECTRICAL CHARACTERISTICS (T _{amb} = - 40 °C to 100 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT		·							
Input forward voltage	I _F = 16 mA		V _F		1.4	1.8	V		
Input reverse current	V _R = 3 V		I _R		0.5	10	μA		
Input capacitance	f = 1 MHz, V_F = 0 V, T_{amb} = 25 °C		C _{IN}		75		pF		
Temperature coefficient of forward voltage	I _F = 16 mA		$\Delta V_F / \Delta T_{amb}$		- 1.7		mV/°C		
OUTPUT						•	•		
Logic low supply current	I_F = 16 mA, V_O = open, V_{CC} = 15 V		I _{CCL}		200		μA		
Logic high supply current	$I_{F} = 0 \text{ mA}, V_{O} = \text{open}, V_{CC} = 15 \text{ V}, \\ T_{amb} = 25 \text{ °C}$		I _{CCH}		0.001	1	μA		
	$I_F = 0$ mA, $V_O =$ open, $V_{CC} = 15$ V		I _{CCH}			1.8 10	μA		
Logic low output voltage	$I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_{O} = 3 \text{ mA}, \\ T_{amb} = 25 \text{ °C}$		V _{OL}		0.15	0.4	V		
	$I_F = 16 \text{ mA}, V_{CC} = 15 \text{ V}, I_O = 2.4 \text{ mA}$		V _{OL}			0.5	V		
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}, T_{amb} = 25 \text{ °C}$		I _{ОН}		0.003	0.5	μA		
Logic high output current	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, T_{amb} = 25 \text{ °C}$		I _{ОН}		0.01	1	μA		
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$		I _{OH}			50	μA		
COUPLER									
Capacitance (input-output) (1)	f = 1 MHz, T _{amb} = 25 °C		CIO		0.4		pF		

Notes

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements. All typical values are measured at T_{amb} = 25 °C.

 $^{(1)}$ A 0.1 μF bypass capacitor connected between pins 4 and 6 is recommended.

CURRENT TRANSFER RATIO (T _{amb} = - 40 °C to 100 °C, unless otherwise specified)								
PARAMETER TEST CONDITION		SYMBOL	MIN.	TYP.	MAX.	UNIT		
Current transfer ratio (1)(2)	V_{O} = 0.5 V, I_{F} = 16 mA, V_{CC} = 4.5 V	CTR	15	30		%		
	V_{O} = 0.4 V, I _F = 16 mA, T _{amb} = 25 °C		20		50	70		

Notes

⁽¹⁾ Current transfer ratio in percent equals the ratio of output collector current (I_O) to the forward LED input current (I_F) times 100.

(2) A 0.1 µF bypass capacitor connected between pins 4 and 6 is recommended. All typical values are measured at T_{amb} = 25 °C.

SWITCHING CHARACTERISTICS (T _{amb} = - 40 °C to 100 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Propagation delay time to logic low at output (see fig. 1 and note 1)	V_{CC} = 5 V, I_F = 16 mA, R_L = 1.9 $k\Omega$	t _{PHL}		0.2	1	μs			
Propagation delay time to logic high at output (see fig. 1 and note 1)	$\label{eq:V_CC} \begin{array}{l} V_{CC} = 5 \ V, \ I_{F} = 16 \ mA, \\ R_{L} = 1.9 \ k\Omega \end{array}$	t _{PLH}		0.5	1	μs			

Note

⁽¹⁾ The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and the 5.6 k Ω pull-up resistor. All typical values are measured at T_{amb} = 25 °C.

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COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Common mode transient immunity at logic high level output	$\label{eq:RL} \begin{split} R_L &= 1.9 \; k\Omega, \; I_F = 0 \; mA, \\ V_{CM} &= 10 \; V_{P\text{-}P} \end{split}$	VOM452T	CM _H	1			kV/µs		
(see fig. 2 and notes 1, and 2)		VOM453T	CM _H	15			kV/µs		
Common mode transient immunity at logic low level output	$\label{eq:RL} \begin{array}{l} R_{L} = 1.9 \; k\Omega, I_{F} = 16 \; mA, \\ V_{CM} = 10 \; V_{P\text{-}P} \end{array}$	VOM452T	CM _L	1			kV/µs		
(see fig. 2 and notes 1, and 2)		VOM453T	CM _L	15			kV/µs		

Notes

⁽¹⁾ Common mode transient immunity in a logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode pulse (V_{CM}) to assure that the output will remain in a logic high state (i.e., $V_0 > 2 V$). Common mode transient immunity in a logic low level the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal (V_{CM} to assure that the output will remain in logic low state, i.e., $V_0 > 0.8 V$).

 $^{(2)}$ The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and the 5.6 k Ω pull-up resistor.

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Fig. 2 - Test Circuit for Transient Immunity and Typical Waveforms



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SAFETY AND INSULATION RATINGS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Climatic classification (according to IEC 68 part 1)				55/100/21					
Comparative tracking index		CTI	175		399				
Peak transient overvoltage		V _{IOTM}	6000			V			
Peak insulation voltage		VIORM	707			V			
Safety rating - power output		P _{SO}			350	mW			
Safety rating - input current		I _{SI}			150	mA			
Safety rating - temperature		T _{SI}			175	°C			
Creepage distance			5			mm			
Clearance distance			5			mm			

Note

• As per IEC 60747-5-5, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of prodective circuits.

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specfied)



Fig. 3 - Current Transfer Ratio vs. Forward Current



Fig. 5 - Output Current vs. Temperature



Fig. 4 - LED Current vs. LED Forward Voltage



Fig. 6 - Propagation Delay vs. Temperature

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Fig. 7 - Logic High Output Current vs. Temperature



Fig. 8 - Supply Current vs. Temperature



Fig. 9 - Logic Low Output Voltage vs. Temperature



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PACKAGE DIMENSIONS in millimeters



20643

PACKAGE MARKING (example)





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